



DATA SHEET

DC Leakage Current Sensor

PN: CHD_LCT15D5

IPN=10~100mA

Feature

- DC Leakage Current Sensor develops on base of magnetic modulation closed loop principle
- Apply unique patented technology for measure tiny current (mA level)
- This sensor is used to measure current of signal system, circuit, and leakage monitoring system, as well as to measure current difference.
- Supply voltage: DC $\pm 12 \sim 15$ V

Advantages

- High accuracy
- Easy installation
- Wide current measuring range
- Optimized response time
- Low power consumption
- High immunity to external interference

- Very good linearity
- Can be customized

Applications

- The current detection of the lift
- DC panel detection
- The signal system
- Current differential detection
- AC variable-speed drive/ Servo drive
- UPS and Inverter applications



RoHS

Electrical data: ($T_a=25^\circ\text{C}$, $V_c=\pm 15\text{VDC}$)

Parmeter Ref	CHD10 LCT15D5	CHD20 LCT15D5	CHD30L CT15D5	CHD40L CT15D5	CHD50L CT15D5	CHD100 LCT15D5	CHD1000 LCT15D5
Rated input I_{pn}	$\pm 10\text{mA}$ DC	$\pm 20\text{mA}$ DC	$\pm 30\text{mA}$ DC	$\pm 40\text{mA}$ DC	$\pm 50\text{mA}$ DC	$\pm 100\text{mA}$ DC	$\pm 1000\text{mA}$ DC
Measuring range I_p	$0 \sim \pm 15\text{mA}$	$0 \sim \pm 30\text{mA}$	$0 \sim \pm 45\text{mA}$	$0 \sim \pm 60\text{mA}$	$0 \sim \pm 75\text{mA}$	$0 \sim \pm 150\text{mA}$	$0 \sim \pm 1500\text{mA}$
Turns ratio(N_p/N_s) (T)	1:50	1:100	1:150	1:200	1:250	1:400	1:400
Output voltage $V_o(V)$	@ $I_p = \pm I_{pn}$ $\pm 5 \pm 0.5\%$						
Supply voltage $V_c(V)$	$(\pm 12 \sim \pm 15) \pm 5\%$						
Accuracy $X_G(\%)$	@ $I_{PN}, T=25^\circ\text{C}$ $\leq \pm 1$						
Offset voltage $V_{OE}(mV)$	@ $I_p=0, T=25^\circ\text{C}$ $< \pm 50$						
Offset voltage drift $V_{OT}(mV/^\circ\text{C})$	@ $I_p=0, -40 \sim +85^\circ\text{C}$ $\leq \pm 1.5$						
Linearity error $\epsilon_r(\%FS)$	≤ 1.0						



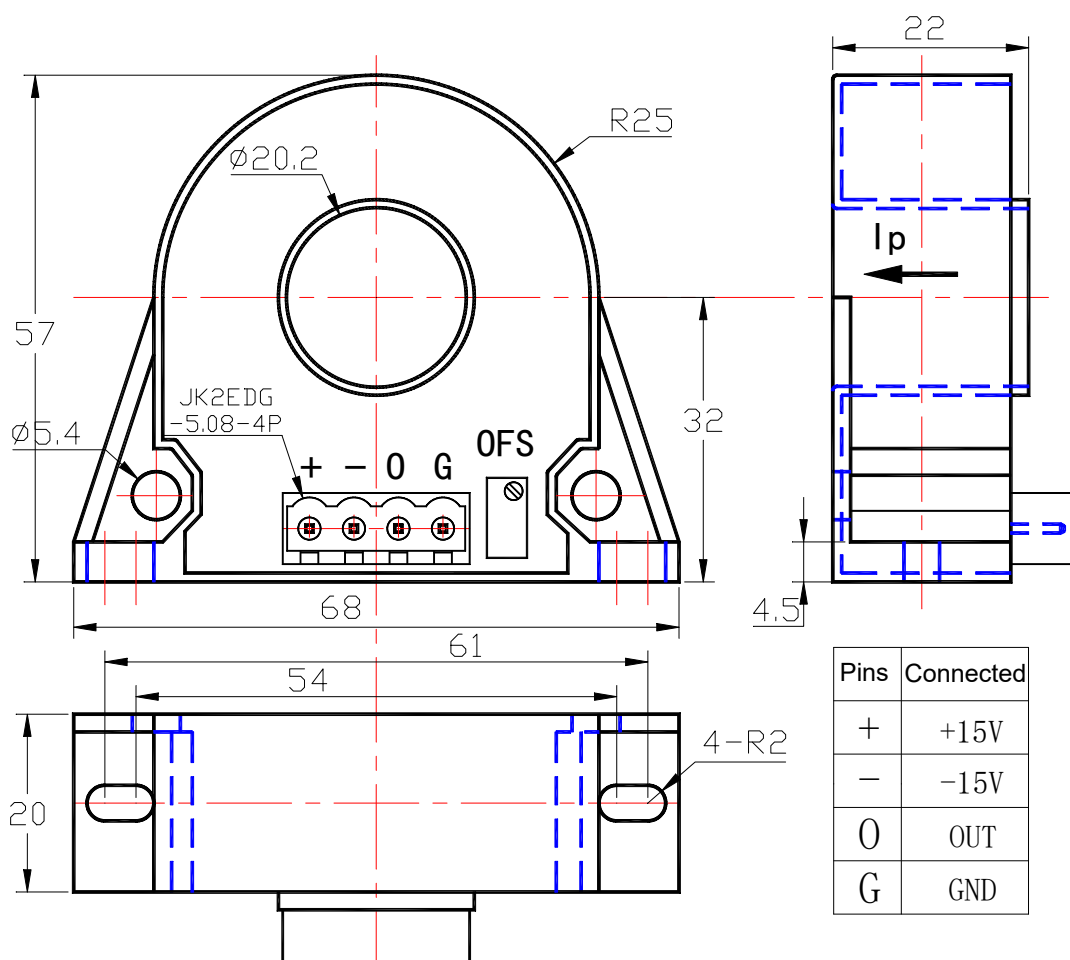
Cheemi Technology Co., Ltd
 Tel: 025-85996365 E-mail: info@cheemi-tech.com www.cheemi-tech.com
 Add: N22, Xianlongwan, Xianyin South Road, Qixia District, Nanjing - China.

Response time $t_{ra}(mS)$	≤ 60	≤ 35
Consumption current (mA)	$20+I_p X(N_p/N_s)$	
Insulation voltage $V_d(KV)$	@50/60Hz, 1min, AC	2.5

General data:

Parameter	Value
Operating temperature $T_A(^{\circ}C)$	-40 ~ +85
Storage temperature $T_S(^{\circ}C)$	-40 ~ +125
Mass $M(g)$	99
Plastic material	PBT G30/G15, UL94- V0;
Standards	IEC60950-1:2001
	EN50178:1998
	SJ20790-2000

Dimensions(mm):



General tolerance: $\leq \pm 0.5mm$

Primary through-hole: $D20.2 \pm 0.15mm$



Characteristics chart:

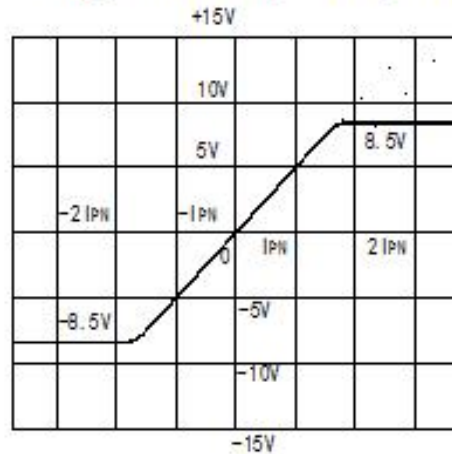
Characteristic of Output Noise Voltage



输出噪声电压
(Noise voltage)

Input Current-Output Voltage

Primary Current (I_p) — Output (V)



Remarks:

- When the current goes through the primary pin of a sensor, the voltage will be measured at the output end.
- Custom design is available for the different rated input current and the output voltage.
- The dynamic performance is the best when the primary hole is fully filled with.
- The primary conductor should be $<100^{\circ}\text{C}$.

WARNING : Incorrect wiring may cause damage to the sensor.



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